

**IN THE CLAIMS:**

1        1-18.    (Cancelled)

1        19.    (Original) A multi-wavelength laser light emitting apparatus comprising:  
2                a plurality of semiconductor laser array apparatuses, each of which emits a laser  
3 light of a different wavelength; and  
4                an optical component that condenses each emitted laser light at a predetermined  
5 point,  
6                wherein at least one of the plurality of semiconductor laser array apparatuses  
7 includes a laser array structure where a plurality of light waveguides are formed between a  
8 plurality of current blocking elements, and  
9                at least two adjacent light waveguides are optically connected to each other.

1        20.    (Original) The multi-wavelength laser light emitting apparatus of Claim 19,  
2 further comprising:  
3                an adjusting means for displacing the optical component to condense each emitted  
4 laser light at the predetermined point;  
5                a laser driving means for selecting and exciting a semiconductor laser array  
6 apparatus that emits a laser light of a specified wavelength; and  
7                a control means for controlling the adjusting means according to the specified  
8 wavelength.

1        21.    (Original) The multi-wavelength laser light emitting apparatus of Claim 20,  
2                wherein each of the plurality of semiconductor laser array apparatuses includes:

3 a substrate;  
4 a plurality of current blocking elements that are stripe shaped and are formed on  
5 the substrate; and  
6 a plurality of light waveguides that are formed between the plurality of current  
7 blocking elements,  
8 wherein at least two adjacent light waveguides are optically connected by  
9 removing a part of each current blocking element therebetween.

1 22. (Original) The multi-wavelength laser light emitting apparatus of Claim 20,  
2 wherein each of the plurality of semiconductor laser array apparatuses includes:  
3 a substrate;  
4 a plurality of current blocking elements that are formed on the substrate; and  
5 a plurality of light waveguides that are formed between the plurality of current  
6 blocking elements,  
7 wherein at least two adjacent light waveguides are bent and connected via at least  
8 one point.

1 23. (Original) The multi-wavelength laser light emitting apparatus of Claim 20,  
2 wherein each of the plurality of semiconductor laser array apparatuses includes:  
3 a substrate that includes a first end face and a second end face opposing to each  
4 other;  
5 a current blocking element that is formed on the substrate, first grooves and  
6 second grooves being formed in the current blocking element, the first grooves extending in

7 parallel from the first end face toward the second end face, and the second grooves extending in  
8 parallel from the second end face toward the first end face;  
9 first light waveguides that are respectively formed in the first grooves; and  
10 second light waveguides that are respectively formed in the second grooves,  
11 wherein the first and second light waveguides are alternatively arranged in an  
12 arrangement direction thereof.

1 24-50. (Cancelled)

1 51. (New) The multi-wavelength laser light emitting apparatus of Claim 19  
2 wherein more than two light waveguides are arranged in parallel, and further  
3 including a single connection waveguide crossing the plurality of parallel waveguides along a  
4 straight line which crosses and connects each of the waveguides at a slanted angle.